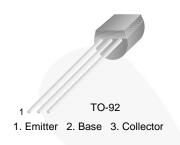
February 2015



2N5550 NPN Epitaxial Silicon Transistor

Features

- Amplifier Transistor
- Collector-Emitter Voltage: V_{CEO} = 140 V



Ordering Information

Part Number	Part Number Top Mark		Packing Method	
2N5550BU	2N5550	TO-92 3L	Bulk	
2N5550TA	2N5550	TO-92 3L	Ammo	
2N5550TAR	2N5550	TO-92 3L	Ammo	
2N5550TF	2N5550	TO-92 3L	Tape and Reel	
2N5550TFR	2N5550	TO-92 3L	Tape and Reel	

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	160	V
V _{CEO}	Collector-Emitter Voltage	140	V
V _{EBO}	Emitter-Base Voltage	6	V
۱ _C	Collector Current	600	mA
ТJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to 150	°C

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Thermal Characteristics⁽¹⁾

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Max.	Unit
Б	Total Device Dissipation	625	mW
PD	Derate Above 25°C	5.0	mW/°C
R _{θJA}	Thermal Resistance, Junction-to-Ambient	200	°C/W

Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

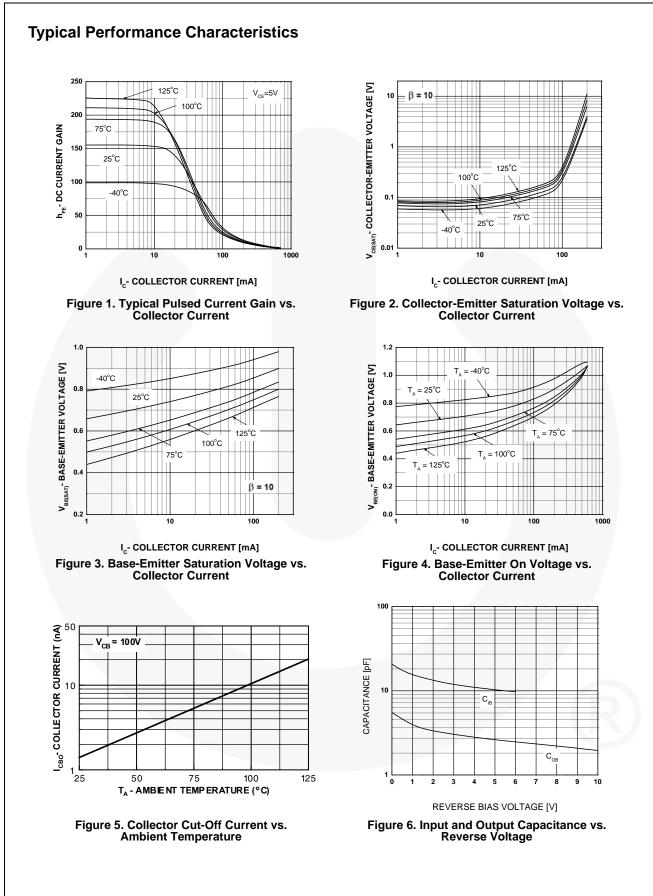
Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	160			V
BV _{CEO}	Collector-Emitter Breakdown Voltage ⁽²⁾	$I_{\rm C} = 1 {\rm mA}, I_{\rm B} = 0$	140			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, \ I_{C} = 0$	6			V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 100 \text{ V}, I_{E} = 0$			100	nA
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 4 V, I_{C} = 0$			50	nA
h _{FE}		$I_{C} = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	60			
	DC Current Gain ⁽²⁾	I _C = 10 mA, V _{CE} = 5 V	60		250	
		I _C = 50 mA, V _{CE} = 5 V	20			
) (t)	Collector-Emitter Saturation Voltage ⁽²⁾	I _C = 10 mA, I _B = 1 mA			0.15	v
V _{CE} (sat)		$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5 \text{ mA}$			0.25	Ň
V _{BE} (sat) E	Base-Emitter Saturation Voltage ⁽²⁾	I _C = 10 mA, I _B = 1 mA			1.0	V
		$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5 \text{ mA}$			1.2	
f _T	Current Gain Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 10 \text{ V}$ f = 100 MHz	100		300	MHz
C _{ob}	Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 1 MHz			6	pF
NF	Noise Figure	$ I_C = 250 \ \mu\text{A}, \ V_{CE} = 5 \ \text{V}, \\ R_S = 1 \ \text{k}\Omega, f = 10 \ \text{Hz to} \\ 15.7 \ \text{kHz} $			10	dB

Note:

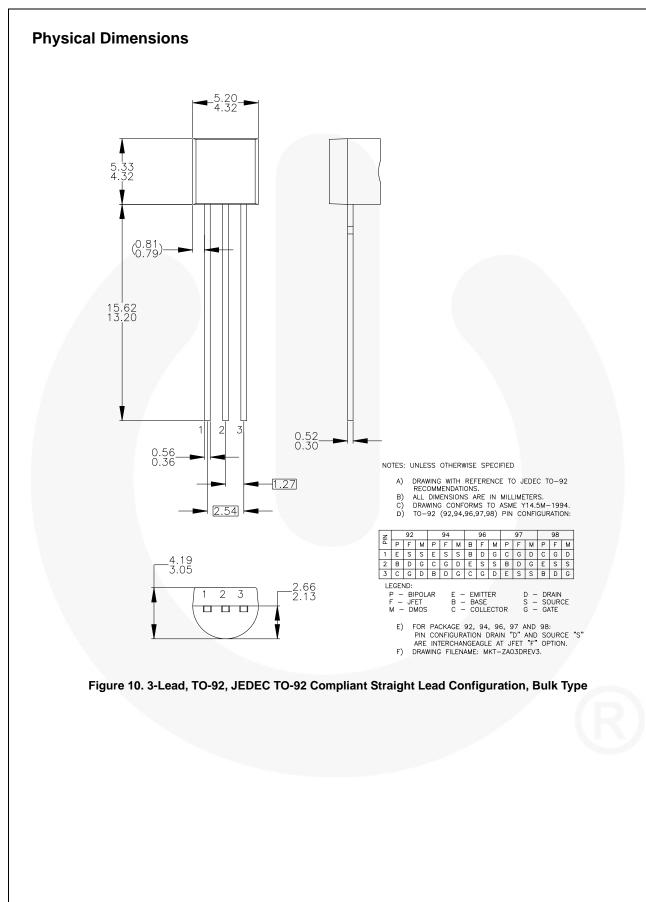
2. Pulse test: pulse width $\leq 300~\mu s,~duty~cycle \leq 2\%$

2N5550 — NPN Epitaxial Silicon Transistor

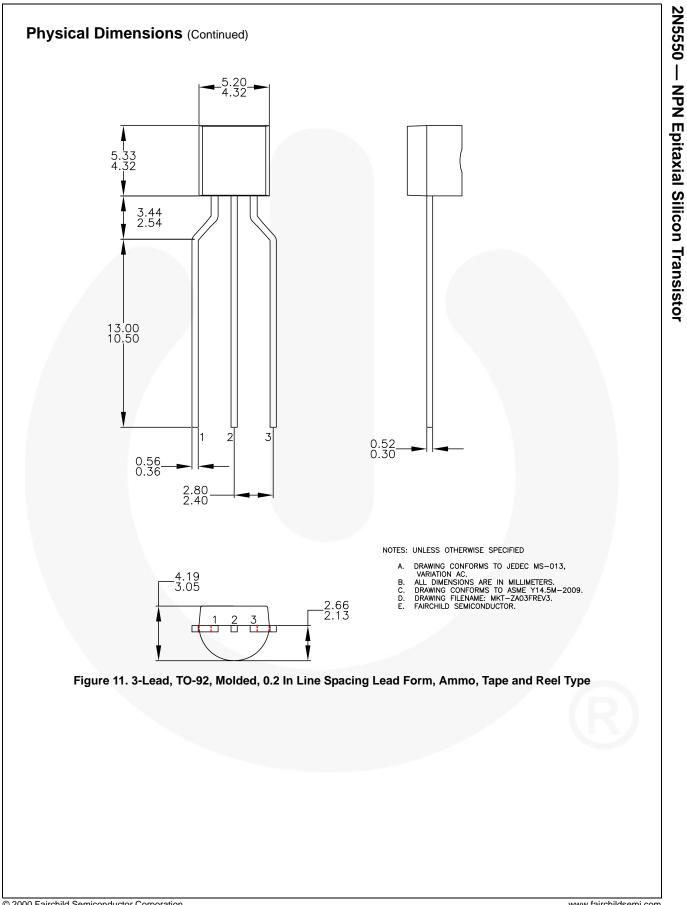


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Typical Performance Characteristics (Continued) 260 240 240 220 220 200 200 180 h FE - SMALL SIGNAL CURRENT GAIN 16 FREG = 20 MHz = 1.0 mA Ιc V_{CE} = 10V 12 8 4 BV CER-′160 ⊾ 0.1 0 1 10 100 1000 10 50 1 **RESISTANCE** (kΩ) I c - COLLECTOR CURRENT (mA) Figure 8. Small Signal Current Gain vs. Collector Current Figure 7. Collector- Emitter Breakdown Voltage with Resistance between Emitter-Base 700 **P** - **POWER DISSIPATION (mW)** 200 - 200 100 100 **P** - **P** TO-92 SOT-23 0 50 75 100 TEMPERATURE (°C) 0 25 125 150 Figure 9. Power Dissipation vs. Ambient Temperature



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